



PBL1501Y

15 V PNP BISS loadswitch

30 January 2023

Product data sheet

1. General description

Low V_{CEsat} PNP transistor and NPN resistor-equipped transistor encapsulated in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- Low V_{CEsat} (BISS) transistor and resistor-equipped transistor in one package
- Low 'threshold' voltage (< 1 V) compared to MOSFET
- Low drive power required
- Space-saving solution
- Reduction of component count
- AEC-Q101 qualified

3. Applications

- Supply line switches
- Battery charger switches
- High-side switches for LEDs, drivers and backlights
- Portable equipment

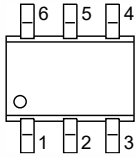
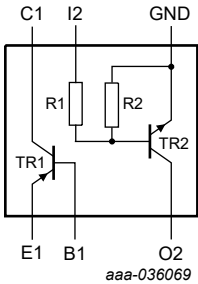
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
TR1: PNP low V_{CEsat} transistor						
V_{CEO}	collector-emitter voltage	open base	-	-	-15	V
I_C	collector current		-	-	-500	mA
R_{CEsat}	collector-emitter saturation resistance	$I_C = -500$ mA; $I_B = -50$ mA; $T_{amb} = 25$ °C; pulsed; $t_p \leq 300$ μ s; $\delta_{factor} \leq 0.02$	-	300	500	m Ω
TR2: NPN Resistor-Equipped Transistor (RET)						
V_{CEO}	collector-emitter voltage	open base	-	-	50	V
I_O	output current		-	-	100	mA
R1	bias resistor 1 (input)		1.54	2.2	2.86	k Ω
R2/R1	bias resistor ratio		0.8	1	1.2	

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1	 TSSOP6 (SOT363)	 aaa-036069
2	B1	base TR1		
3	O2	output (collector) TR2		
4	GND	GND (emitter) TR2		
5	I2	input (base) TR2		
6	C1	collector TR1		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PBLS1501Y	TSSOP6	plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	SOT363

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PBLS1501Y	%C1

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
TR1: PNP low V_{CEsat} transistor						
V_{CBO}	collector-base voltage	open emitter		-	-15	V
V_{CEO}	collector-emitter voltage	open base		-	-15	V
V_{EBO}	emitter-base voltage	open collector		-	-6	V
I_C	collector current			-	-500	mA
I_{CM}	peak collector current	$t_p \leq 1$ ms; single pulse; $\delta \leq 0.02$		-	-1	A
I_B	base current			-	-50	mA
I_{BM}	peak base current	$\delta \leq 0.02$; single pulse; $t_p \leq 1$ ms		-	-100	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C	[1]	-	200	mW
TR2: NPN Resistor-Equipped Transistor (RET)						
V_{CBO}	collector-base voltage	open emitter		-	50	V
V_{CEO}	collector-emitter voltage	open base		-	50	V
V_{EBO}	emitter-base voltage	open collector		-	10	V
V_I	input voltage	input voltage TR2 positive		-	12	V
		input voltage TR2 negative		-	-10	V
I_O	output current			-	100	mA
I_{CM}	peak collector current	$t_p \leq 1$ ms; single pulse		-	100	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C	[1]	-	200	mW
Per device						
P_{tot}	total power dissipation			-	300	mW
T_j	junction temperature			-	150	°C
T_{amb}	ambient temperature			-65	150	°C
T_{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	416	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
TR1: PNP low V_{CEsat} transistor							
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = -100 \mu A$; $I_E = 0 A$; $T_{amb} = 25^\circ C$		-15	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = -10 mA$; $I_B = 0 A$; $T_{amb} = 25^\circ C$		-15	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	$I_C = 0 A$; $I_E = 100 \mu A$; $T_{amb} = 25^\circ C$		-6	-	-	V
I_{CBO}	collector-base cut-off current	$V_{CB} = -15 V$; $I_E = 0 A$; $T_{amb} = 25^\circ C$		-	-	-100	nA
		$V_{CB} = -15 V$; $I_E = 0 A$; $T_{amb} = 150^\circ C$		-	-	-50	μA
I_{CES}	collector-emitter cut-off current	$V_{CE} = -15 V$; $V_{BE} = 0 V$; $T_{amb} = 25^\circ C$		-	-	-100	nA
I_{EBO}	emitter-base cut-off current	$V_{EB} = -5 V$; $I_C = 0 mA$; $T_{amb} = 25^\circ C$		-	-	-100	nA
h_{FE}	DC current gain	$V_{CE} = -2 V$; $I_C = -10 mA$; pulsed; $T_{amb} = 25^\circ C$		200	-	-	
		$V_{CE} = -2 V$; $I_C = -100 mA$; pulsed; $t_p \leq 300 \mu s$; $\delta \leq 0.02$; $T_{amb} = 25^\circ C$		150	-	-	
		$V_{CE} = -2 V$; $I_C = -500 mA$; pulsed; $t_p \leq 300 \mu s$; $\delta \leq 0.02$; $T_{amb} = 25^\circ C$		90	-	-	
V_{CEsat}	collector-emitter saturation voltage	$I_C = -10 mA$; $I_B = -0.5 mA$; $T_{amb} = 25^\circ C$		-	-	-25	mV
		$I_C = -200 mA$; $I_B = -10 mA$; $T_{amb} = 25^\circ C$		-	-	-150	mV
		$I_C = -500 mA$; $I_B = -50 mA$; pulsed; $t_p \leq 300 \mu s$; $\delta \leq 0.02\%$; $T_{amb} = 25^\circ C$		-	-	-250	mV
R_{CEsat}	collector-emitter saturation resistance	$I_C = -500 mA$; $I_B = -50 mA$; $T_{amb} = 25^\circ C$; pulsed; $t_p \leq 300 \mu s$; $\delta_{factor} \leq 0.02$		-	300	500	m Ω
V_{BEsat}	base-emitter saturation voltage			-	-	-1.1	V
V_{BEon}	base-emitter turn-on voltage	$V_{CE} = -2 V$; $I_C = -100 mA$; $T_{amb} = 25^\circ C$; pulsed; $t_p \leq 300 \mu s$; $\delta_{factor} \leq 0.02$		-	-	-0.9	V
C_c	collector capacitance	$V_{CB} = -10 V$; $I_E = 0 A$; $i_e = 0 A$; $f = 1 MHz$; $T_{amb} = 25^\circ C$		-	-	10	pF
f_T	transition frequency	$V_{CE} = -5 V$; $I_C = -100 mA$; $f = 100 MHz$; $T_{amb} = 25^\circ C$		100	280	-	MHz
TR2: NPN Resistor-Equipped Transistor (RET)							
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 100 \mu A$; $I_E = 0 A$; $T_{amb} = 25^\circ C$		50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 10 mA$; $I_B = 0 A$; $T_{amb} = 25^\circ C$		50	-	-	V
I_{CBO}	collector-base cut-off current	$V_{CB} = 50 V$; $I_E = 0 A$; $T_{amb} = 25^\circ C$		-	-	100	nA
I_{CEO}	collector-emitter cut-off current	$V_{CE} = 30 V$; $I_B = 0 A$; $T_{amb} = 25^\circ C$		-	-	1	μA
		$V_{CE} = 30 V$; $I_B = 0 A$; $T_{amb} = 150^\circ C$		-	-	50	μA
I_{EBO}	emitter-base cut-off current	$V_{EB} = 5 V$; $I_C = 0 A$; $T_{amb} = 25^\circ C$		-	-	2	mA
h_{FE}	DC current gain	$V_{CE} = 5 V$; $I_C = 20 mA$; $T_{amb} = 25^\circ C$		30	-	-	

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CEsat}	collector-emitter saturation voltage	$I_C = 10\text{ mA}$; $I_B = 0.5\text{ mA}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$	-	-	150	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5\text{ V}$; $I_C = 1\text{ mA}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$	-	1.2	0.5	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = 0.3\text{ V}$; $I_C = 20\text{ mA}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$	2	1.6	-	V
R1	bias resistor 1 (input)		1.54	2.2	2.86	k Ω
R2/R1	bias resistor ratio		0.8	1	1.2	
C_c	collector capacitance	$V_{CB} = 10\text{ V}$; $I_E = 0\text{ A}$; $i_e = 0\text{ A}$; $f = 1\text{ MHz}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$	-	-	2.5	pF

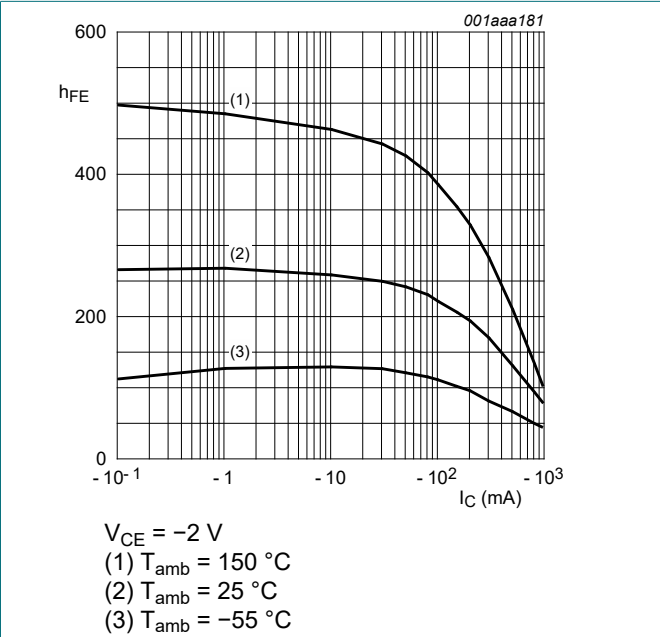


Fig. 1. TR1 (PNP): DC current gain as a function of collector current; typical values

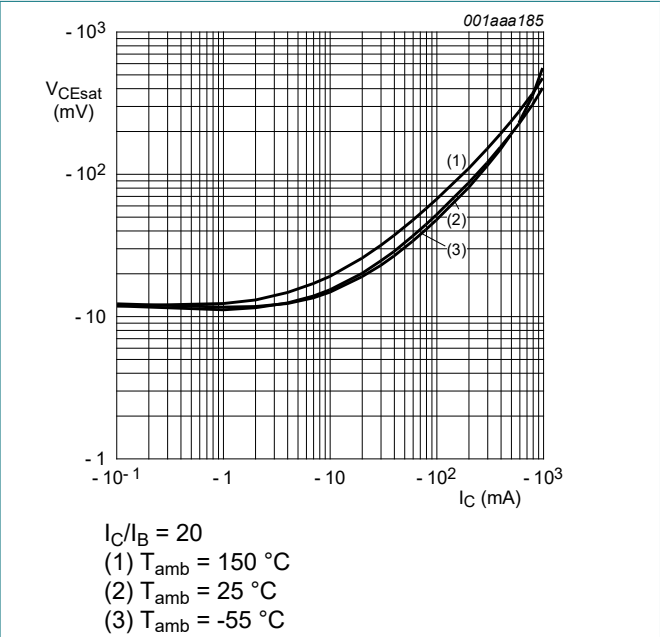


Fig. 2. TR1 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values

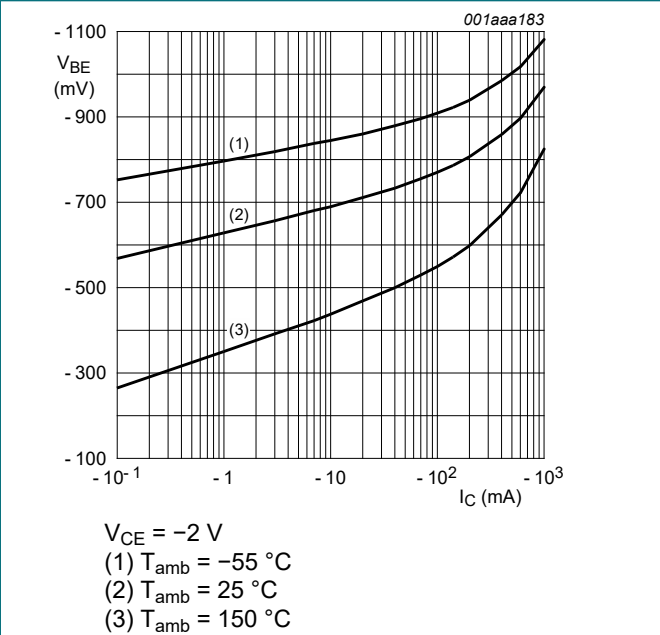


Fig. 3. TR1 (PNP): Base-emitter voltage as a function of collector current; typical values

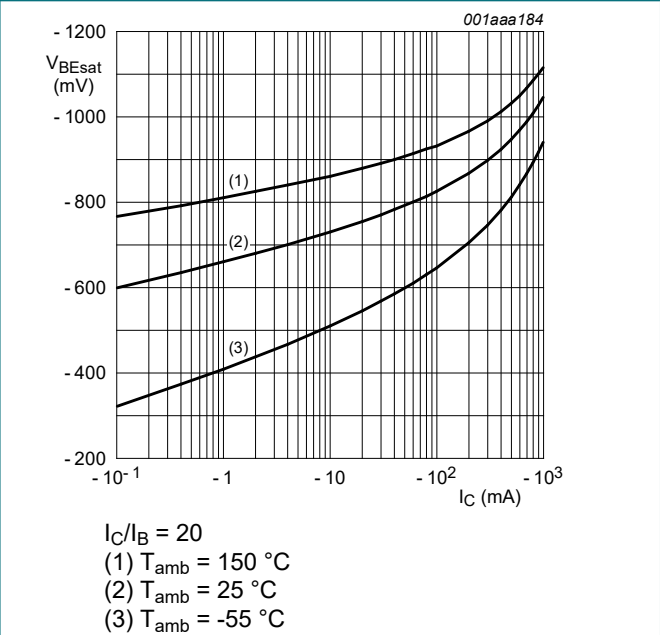
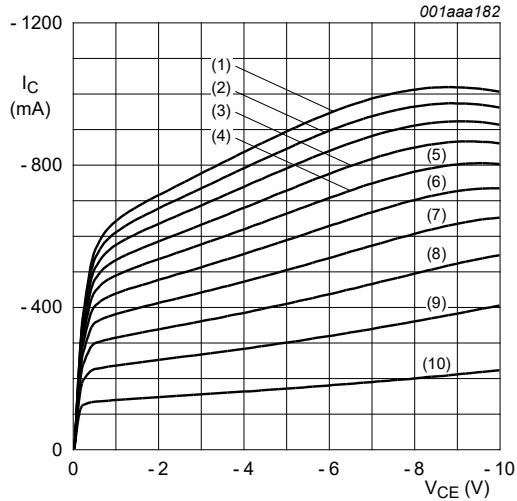
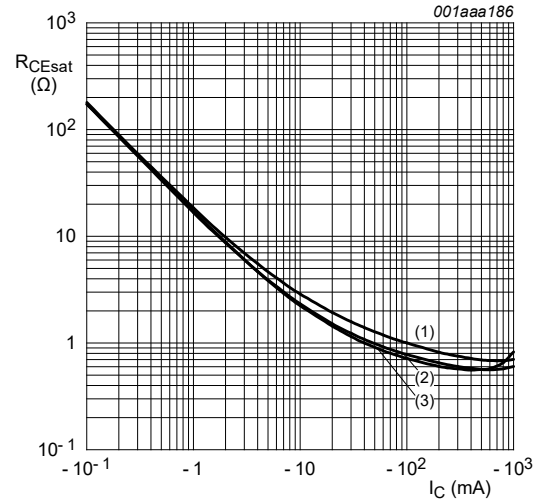


Fig. 4. TR1 (PNP): Base-emitter saturation voltage as a function of collector current; typical values



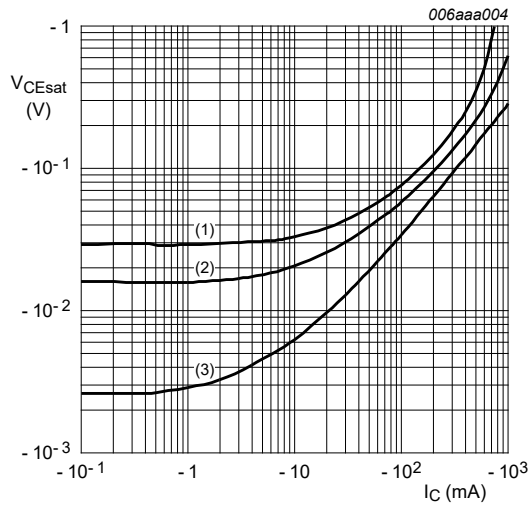
$T_{amb} = 25\text{ }^{\circ}\text{C}$
 (1) $I_B = -7.0\text{ mA}$
 (2) $I_B = -6.3\text{ mA}$
 (3) $I_B = -5.6\text{ mA}$
 (4) $I_B = -4.9\text{ mA}$
 (5) $I_B = -4.2\text{ mA}$
 (6) $I_B = -3.5\text{ mA}$
 (7) $I_B = -2.8\text{ mA}$
 (8) $I_B = -2.1\text{ mA}$
 (9) $I_B = -1.4\text{ mA}$
 (10) $I_B = -0.7\text{ mA}$

Fig. 5. TR1 (PNP): Collector current as a function of collector-emitter voltage; typical values



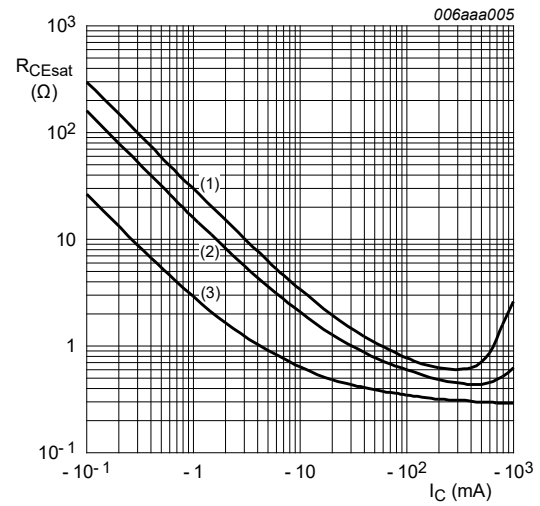
$I_C/I_B = 20$
 (1) $T_{amb} = -55\text{ }^{\circ}\text{C}$
 (2) $T_{amb} = 25\text{ }^{\circ}\text{C}$
 (3) $T_{amb} = 150\text{ }^{\circ}\text{C}$

Fig. 6. TR1 (PNP): Equivalent on-resistance as a function of collector current; typical values



$T_{amb} = 25\text{ }^{\circ}\text{C}$
 (1) $I_C/I_B = 100$
 (2) $I_C/I_B = 50$
 (3) $I_C/I_B = 10$

Fig. 7. TR1 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values



$T_{amb} = 25\text{ }^{\circ}\text{C}$
 (1) $I_C/I_B = 100$
 (2) $I_C/I_B = 50$
 (3) $I_C/I_B = 10$

Fig. 8. TR1 (PNP): Equivalent on-resistance as a function of collector current; typical values

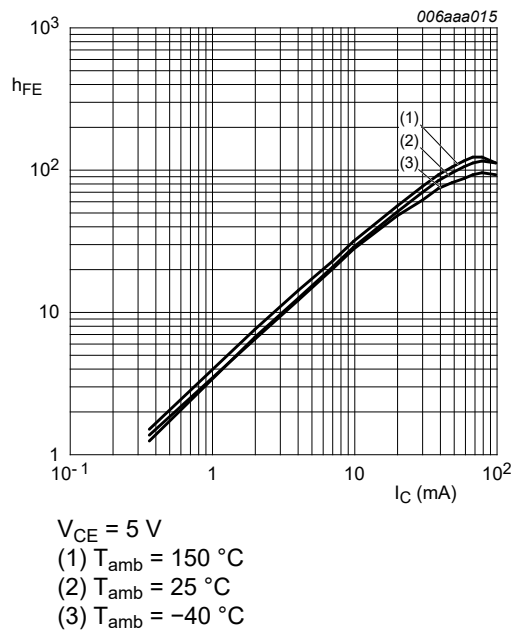


Fig. 9. TR2 (NPN): DC current gain as a function of collector current; typical values

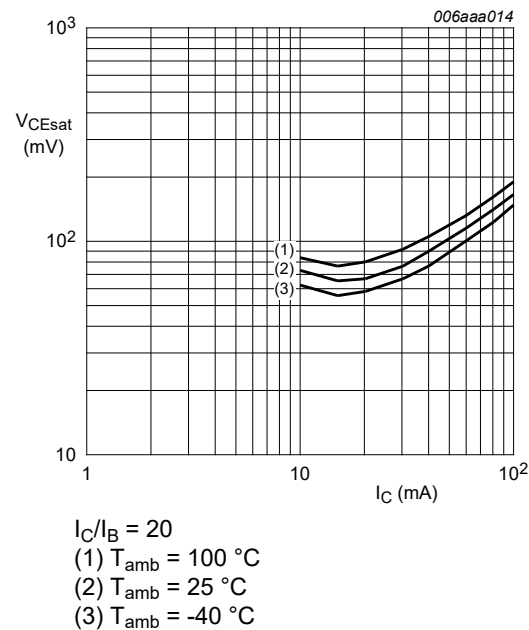


Fig. 10. TR2 (NPN): Collector-emitter saturation voltage as a function of collector current; typical values

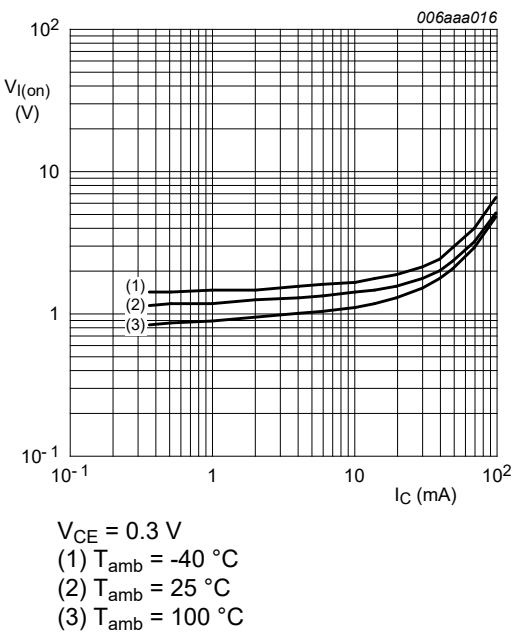


Fig. 11. TR2 (NPN): On-state input voltage as a function of collector current; typical values

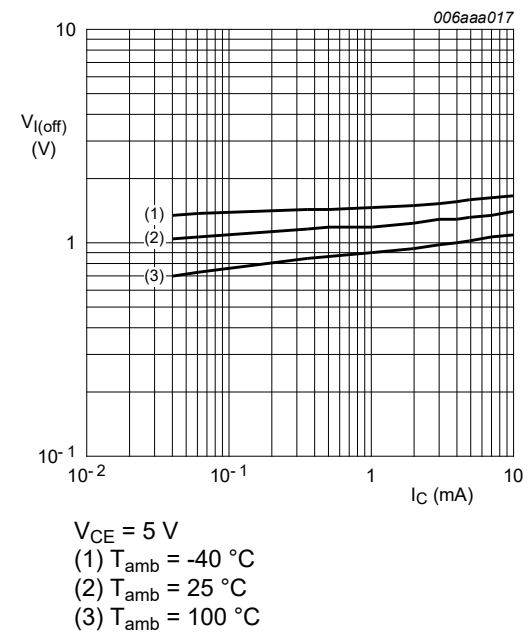


Fig. 12. TR2 (NPN): Off-state input voltage as a function of collector current; typical values

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

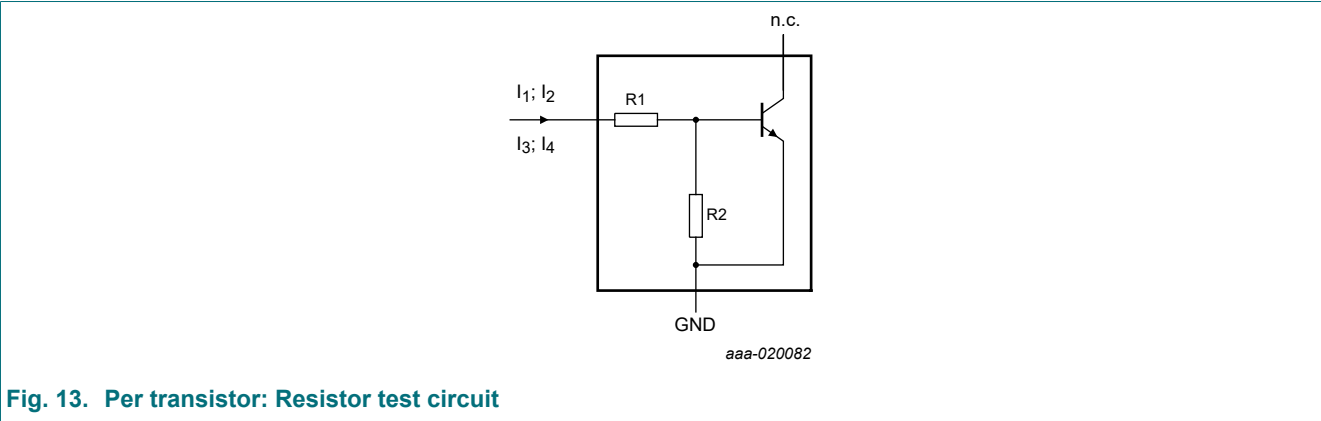
Resistor calculation

- Calculation of bias resistor 1 (R1)

$$R_1 = \frac{V(I_2) - V(I_1)}{I_2 - I_1}$$

- Calculation of bias resistor ratio (R2/R1)

$$\frac{R_2}{R_1} = \frac{V(I_4) - V(I_3)}{R_1 \cdot (I_4 - I_3)} - 1$$



Resistor test conditions

Table 8. Resistor test conditions

TR2 (NPN)	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I ₁	I ₂	I ₃	I ₄
PBLS1501Y	2.2	2.2	750 μA	950 μA	-750 μA	-950 μA

12. Package outline

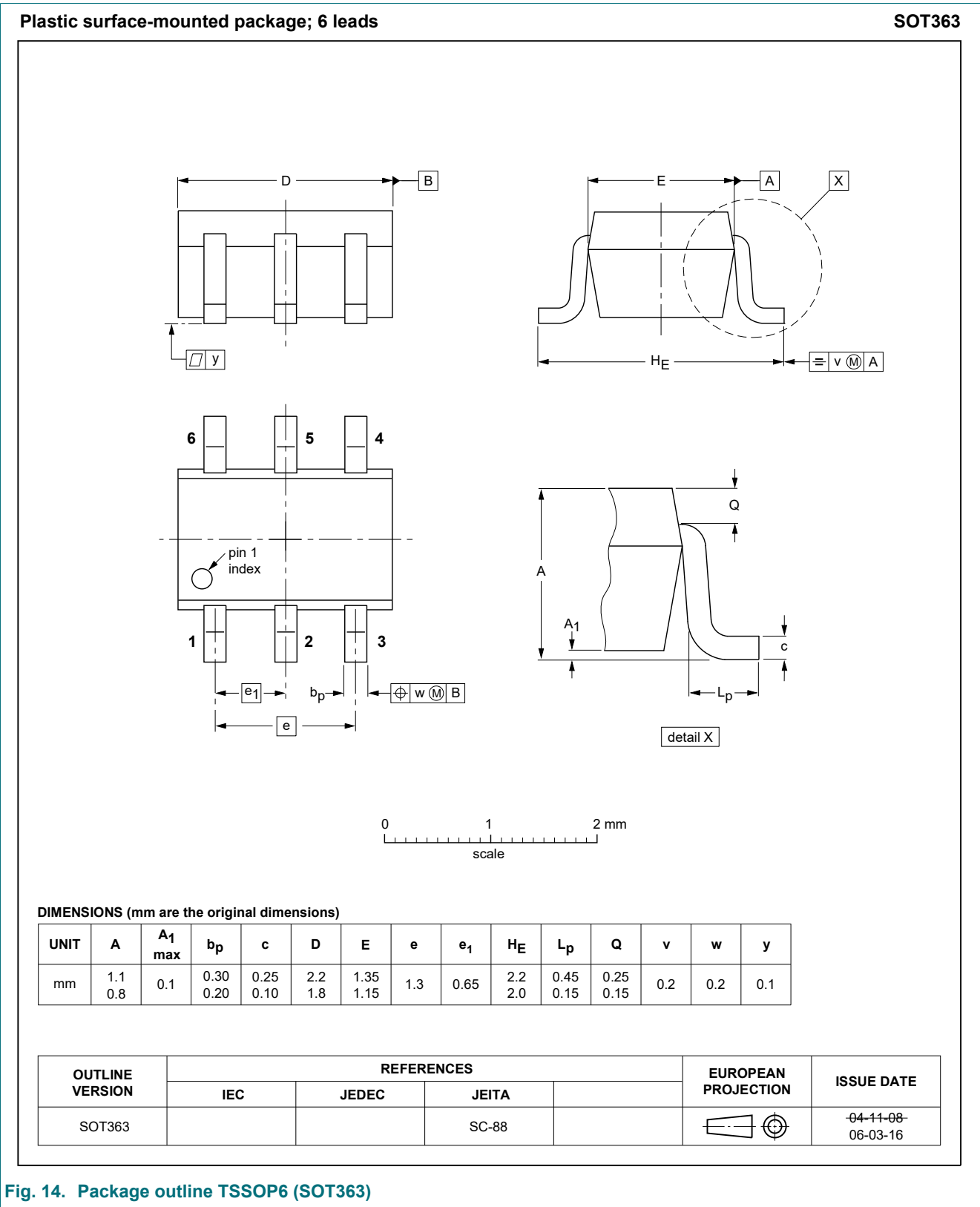


Fig. 14. Package outline TSSOP6 (SOT363)

13. Soldering

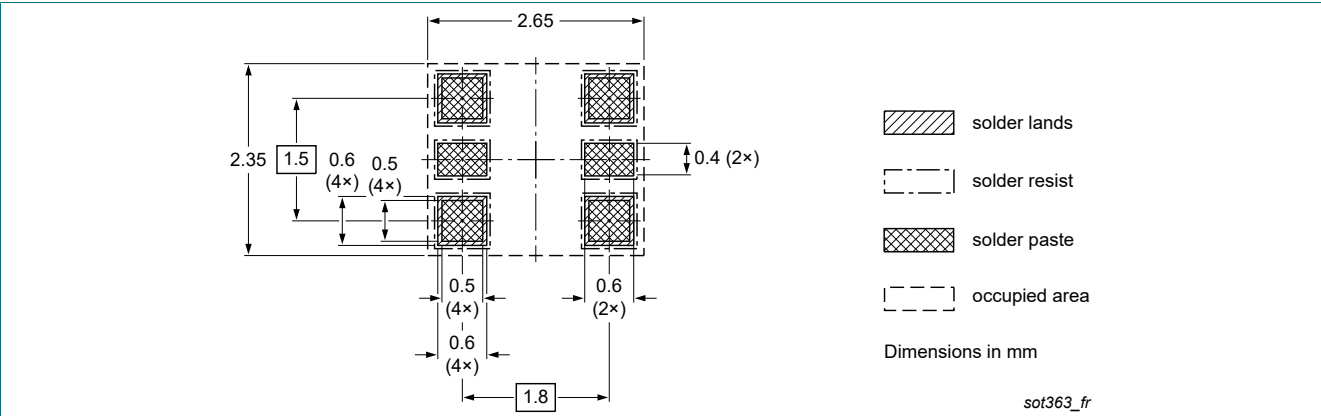


Fig. 15. Reflow soldering footprint for TSSOP6 (SOT363)

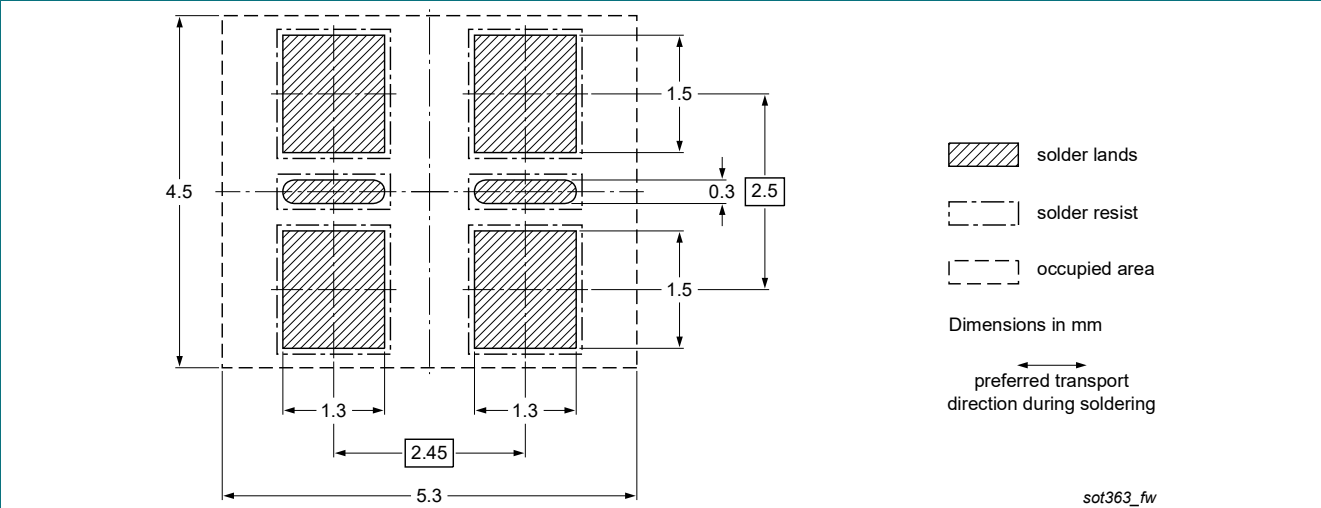


Fig. 16. Wave soldering footprint for TSSOP6 (SOT363)

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBLS1501Y v.4	20230130	Product data sheet	-	PBLS1501Y v.3
Modifications:	- Characteristics: collector-emitter cut-off current added - Test information corrected			
PBLS1501Y v.3	20221228	Product data sheet	-	PBLS1501Y_PBLS1501V_2
PBLS1501Y_PBLS1501V_2	20090824	Product data sheet	-	PBLS1501Y_PBLS1501V_1
PBLS1501Y_PBLS1501V_1	20041105	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

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